

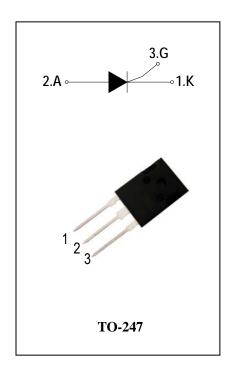
SCRs

General Description

The 55A SCR series of silicon controlled rectifiers, with high ability to withstand the shock loading of large current, provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

Features

- ◆ Repetitive Peak Off-State Voltage: 1600V
- ◆ R.M.S On-State Current (IT(RMS)=55 A)
- ♦ These are Pb-Free Devices



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Repetitive Peak Off-State Voltage	T:-05°C AD055A4C0V		1600	V
V_{RRM}	Repetitive peak reverse voltage	Tj=25°C	ADS55A160K	1600	V
I _{T(AV)}	Average On-State Current	Half Sine Wave , Tc = 85°C		35	Α
I _{T(RMS)}	R.M.S On-State Current	Half Sine Wave , Tc = 85°C		55	Α
I _{TSM}	Surge On-State Current	1/2 Cycle, Sine Wave Non-Repetitive, tp=10ms(50Hz)Tj =25°C		550	А
l ² t	I ² t for Fusing	Tj =25°C,tp =10ms		1500	A^2S
P _{GM}	Forward Peak Gate Power Dissipation	Tj =125°C, Pulse Width ≤ 20μs		10	W
$P_{G(AV)}$	Forward Average Gate Power Dissipation	Tj =25°C, tp =10ms		1	W
I _{GM}	Peak Gate Current	Tj =125°C, Pulse Width ≤ 20μs		5	Α
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C







Electrical Characteristics (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS55A160K			Unit	
·				S	Blank	W	<u> </u>	
I _{DRM}	Peak Forward Reverse	V _{DRM} = V _{RRM} Tj = 25°C		10			uA	
I _{RRM}	Blocking Current	V _{DRM} = V _{RRM} Tj = 125°C	Max.			mA		
V _{TM}	Peak On-State Voltage	$I_{TM} = 80A$, $t_p = 380 \ \mu s$	Max.	1.8		V		
$V_{\sf GD}$	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V		
V_{GT}	Gate Trigger Voltage	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Max.	1.5		V		
I _{GT}	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	15	30	80	mA	
Ι _Η	Holding Current	I _T = 0.5A	Max.	30	40	150	mA	
ΙL	Latching Current	I _G = 1.2 I _{GT}	Max.	50	60	200	mA	
dV/dt	Critical Rate of Rise of Off-State Voltage	$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	700	1000	1500	V/µs	
R _{th(j-c)}	Junction to case (AC)		Max.	0.6		°C/W		
R _{th(j-a)}	Junction to ambient		Max.	50			°C/W	

FIG.2: Average on-state current VS Allowable

case Temperature(Single phase half wave)

120

ADV

FIG.1: Maximum average power dissipation (Single phase half wave)

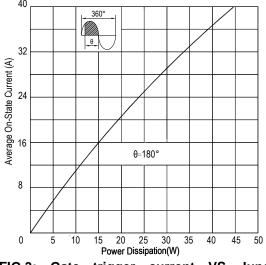


FIG.3: Gate trigger current VS Junction temperature

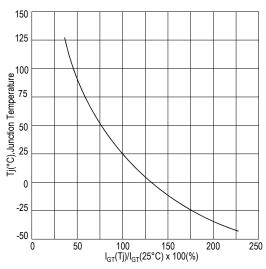
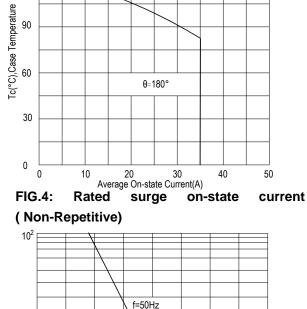
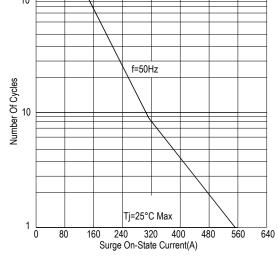
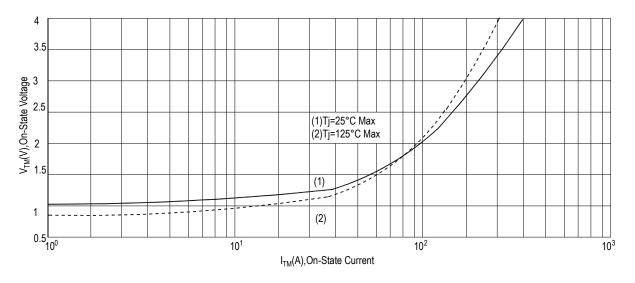


FIG.5: On-state characteristics(Max)









-50

ADS55A160K

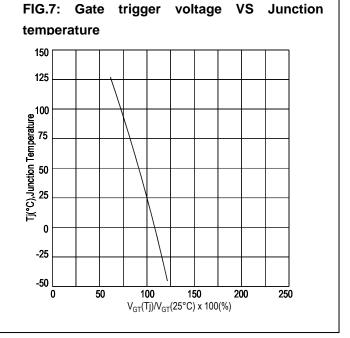
FIG.6:Holding current and Latching current VS

Junction temperature

100

I_H,I_L(Tj)/I_H,I_L(25°C) x 100(%)

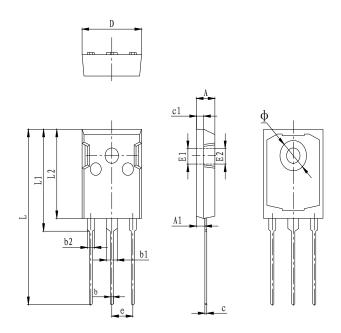
250





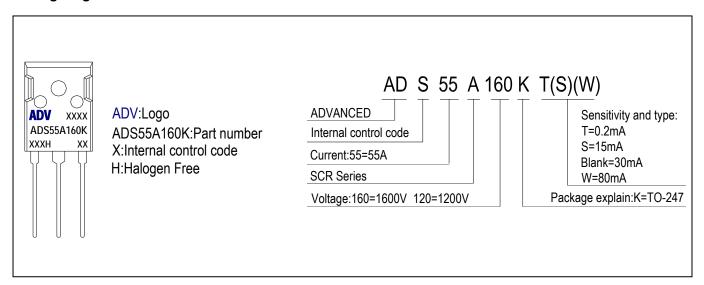
PACKAGE MECHANICAL DATA

TO-247 Package Dimension



	Dimens	sions In	Dimensions In		
Symbol	Millim	neters	Inches		
	Min	Max	Min	Max	
Α	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.500 REF		0.138 REF		
E2	3.600 REF		0.142 REF		
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ф	7.100	7.300	0.280	0.287	
е	5.450 TYP		0.215 TYP		

Making Diagram



Ordering information

Part number	Package	Package Marking		Quantity			
ADS55A160K#	TO-247	ADS55A160K#	Tube	25pcs			
Note:# = Gate Trigger Current Sensitivity and type							



ADS55A160K

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